

Vishay Semiconductors

Small Signal Schottky Diodes

Features

- · For general purpose applications
- These diodes feature very low turn-on voltage and fast switching.



- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- These diodes are also available in the DO35 case with type designations BAT42 to BAT43 and in the SOD123 case with type designations BAT42W-V to BAT43W-V.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Mechanical Data

Case: MiniMELF Glass case (SOD80)

Weight: approx. 31 mg
Cathode Band Color: black
Packaging Codes/Options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
LL42	LL42-GS18 or LL42-GS08	-	Tape and Reel
LL43	LL43-GS18 or LL43-GS08	-	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	30	V
Forward continuous current	T _{amb} = 25 °C	I _F	200 ¹⁾	mA
Repetitive peak forward current	t_p < 1 s, δ < 0.5, T_{amb} = 25 °C	I _{FRM}	500 ¹⁾	mA
Surge forward current	$t_p = 10 \text{ ms}, T_{amb} = 25 ^{\circ}\text{C}$	I _{FSM}	4 ¹⁾	Α
Power dissipation ¹⁾	T _{amb} = 65 °C	P _{tot}	200 ¹⁾	mW

¹⁾ Valid provided that electrodes are kept at ambient temperature

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Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R_{thJA}	300 ¹⁾	K/W
Junction temperature		T _j	125	°C
Ambient operating temperature range		T _{amb}	- 55 to + 125	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	$I_R = 100 \mu A \text{ (pulsed)}$		V _(BR)	30			V
Leakage current ¹⁾	V _R = 25 V		I _R			0.5	μΑ
	V _R = 25 V, T _j = 100 °C		I _R			100	μΑ
Forward voltage ¹⁾	I _F = 200 mA		V _F			1000	mV
	I _F = 10 mA	LL42	V _F			400	mV
	I _F = 50 mA	LL42	V _F			650	mV
	I _F = 2 mA	LL43	V _F	260		330	mV
	I _F = 15 mA	LL43	V _F			450	mV
Diode capacitance	V _R = 1 V, f = 1 MHz		C _D		7		pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}, R_L = 100 \Omega$		t _{rr}			5	ns
Rectification efficieny	$R_L = 15 \text{ k}\Omega, C_L = 300 \text{ pF},$ $f = 45 \text{ MHz}, V_{RF} = 2 \text{ V}$		η_{V}	80			%

 $^{^{1)}}$ Pulse test $t_{p} < 300~\mu s,\,t_{p}/T < 0.02$

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

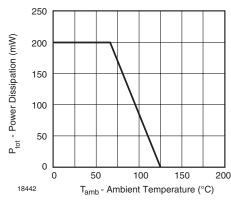


Figure 1. Admissible Power Dissipation vs. Ambient Temperature

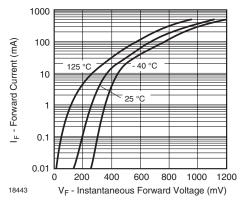


Figure 2. Typical Reverse Characteristics



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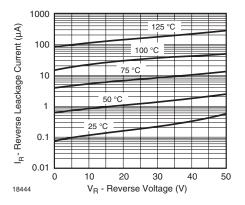


Figure 3. Typical Reverse Characteristics

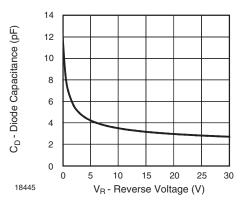
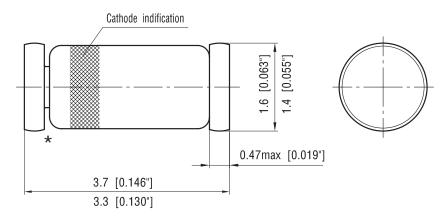
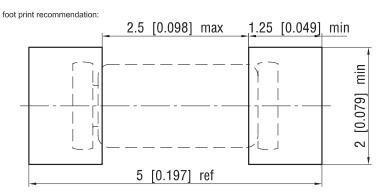


Figure 4. Typical Capacitance vs. Reverse Voltage

Package Dimensions in millimeters (inches): MiniMELF (SOD80)



★ The gap between plug and glass can be either on cathode or anode side



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LL42/LL43

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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